



PRELIMINARY

LH4161A/LH4161/LH4161C High Speed Operational Amplifier

General Description

The LH4161 high-speed amplifier exhibits an excellent speed-power product in delivering 300 V/ μ s and 50 MHz unity gain stability with only 5 mA of supply current. Further power savings and application convenience are possible by taking advantage of the wide dynamic range in operating supply voltage which extends all the way down to +5V.

These amplifiers are built with National's new VIPTM (Vertically Integrated PNP) process which provides fast PNP transistors that are true complements to the already fast NPN devices. This advanced junction-isolated process delivers high-speed performance without the need for complex and expensive dielectric isolation.

In addition, they are precision laser trimmed to guarantee low offset voltage.

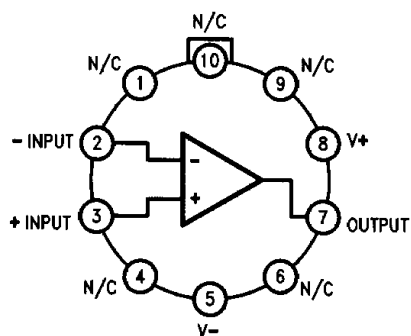
Features

- High slew rate 300 V/ μ s
- High unity gain freq 50 MHz
- Low supply current 5 mA
- Fast settling 120 ns to 0.1%
- Low differential gain <0.1%
- Low differential phase 0.1°
- Wide supply range 4.75V to 32V
- Stable with unlimited capacitive load
- Well behaved, easy to apply
- Low offset voltage ± 1 mV
- Pin compatible with LM6161

Applications

- Low differential gain and phase amplifier
- Fast pulse amplifier
- High frequency filters and oscillators

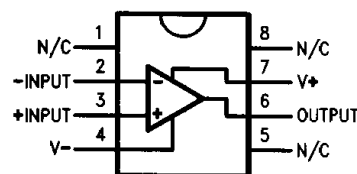
Connection Diagrams



Top View

TL/K/9767-1

Order Number LH4161AH, LH4161H or LH4161CH
See NS Package Number H10F



Top View

TL/K/9767-2

Order Number LH4161AJ, LH4161J or LH4161CJ
See NS Package Number J08A

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage ($V^+ - V^-$)	36V
Differential Input Voltage (Note 8)	$\pm 8V$
CM Voltage	($V^+ - 0.7V$) to ($V^- - 7V$)
Output Short Circuit to GND (Note 1)	Continuous

Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range (Note 2)	
LH4161A/LH4161	-55°C to +125°C
LH4161C	-25°C to +85°C
Max. Junction Temperature	150°C
ESD Tolerance (Notes 8 and 9)	$\pm 700V$
Operating Supply Voltage Range	4.75V to 32V

DC Electrical Characteristics (Note 3)

Parameter	Conditions	Typ	LH4161A		LH4161		LH4161C		Units
			Tested Limit (Note 4)	Design Limit (Note 5)	Tested Limit (Note 4)	Design Limit (Note 5)	Tested Limit (Note 4)	Design Limit (Note 5)	
Input Offset Voltage		0.5	1 3		2 5		4	6	mV Max
Input Offset Voltage Average Drift		10							$\mu V/^{\circ}C$
Input Bias Current		2	3 6		3 6		5	6	μA Max
Input Offset Current		150	350 800		350 800		1500	1900	nA Max
Input Offset Current Average Drift		0.4							nA/ $^{\circ}C$
Input Resistance	Differential	325							k Ω
Input Capacitance	$A_V = +1$ @ 10 MHz	1.5							pF
Large Signal Voltage Gain	$V_{OUT} = \pm 10V$, $R_L = 2 k\Omega$ (Note 11)	750	550 300		550 300		400	350	V/V Min
	$R_L = 10 k\Omega$	2900							V/V
Input Common-Mode Voltage Range	Supply = $\pm 15V$	+14.0	+13.9 +13.8		+13.9 +13.8		+13.8	+13.7	V Min
		-13.2	-12.9 -12.7		-12.9 -12.7		-12.8	-12.7	V Min
	Supply = +5V (Note 6)	4.0	3.9 3.8		3.9 3.8		3.8	3.7	V Min
		1.8	2.0 2.2		2.0 2.2		2.1	2.2	V Max
	$-10V \leq V_{CM} \leq +10V$	94	80 74		80 74		72	70	dB Min
		90	80 74		80 74		72	70	dB Min
Output Voltage Swing	Supply = $\pm 15V$ and $R_L = 2 k\Omega$	+14.2	+13.5 +13.3		+13.5 +13.3		+13.4	+13.3	V Min
		-13.4	-13.0 -12.7		-13.0 -12.7		-12.9	-12.8	V Min
	Supply = +5V and $R_L = 2 k\Omega$ (Note 6)	4.2	3.5 3.3		3.5 3.3		3.4	3.3	V Min
		1.3	1.7 2.0		1.7 2.0		1.8	1.9	V Max
	Source	65	30 20		30 20		30	25	mA Min
		65	30 20		30 20		30	25	mA Min
Supply Current		5.0	6.5 6.8		6.5 6.8		6.8	6.9	mA Max

AC Electrical Characteristics (Notes 3 & 7)

Parameter	Conditions	Typ	LH4161A		LH4161		LH4161C		Units
			Tested Limit (Note 4)	Design Limit (Note 5)	Tested Limit (Note 4)	Design Limit (Note 5)	Tested Limit (Note 4)	Design Limit (Note 5)	
Gain-Bandwidth Product	@F = 20 MHz	50	40		40		35		MHz
	Supply = $\pm 5V$	35							Min
Slew Rate	$A_V = +1$ (Note 10)	300	225		225		200		V/ μs Min
	Supply = $\pm 5V$	200							V/ μs
Power Bandwidth	$V_{OUT} = 20 V_{PP}$	4.5							MHz
Settling Time	10V Step to 0.1% $A_V = -1$, $R_L = 2 k\Omega$	120							ns
Phase Margin		45							Deg
Differential Gain	NTSC, $A_V = +4$	<0.1							%
Differential Phase	NTSC, $A_V = +4$	0.1							Deg
Input Noise Voltage	$f = 10 kHz$	15							nV/ $\sqrt{Hz}$
Input Noise Current	$f = 10 kHz$	1.5							pA/ $\sqrt{Hz}$

Note 1: Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.

Note 2: The typical junction-to-ambient thermal resistance of the cerdip (J) package is 125°C/W, and the TO-5 (H) package is 155°C/W. All numbers apply for packages soldered directly into a printed circuit board.

Note 3: Unless otherwise specified, all limits guaranteed for $T_A = T_J = 25^\circ C$ with supply voltage = $\pm 15V$, $V_{CM} = 0V$, and $R_L \geq 100 k\Omega$. **Boldface** limits apply over the range listed under "Operating Temperature Range" with $T_A = T_J$ in the "Absolute Maximum Ratings" section.

Note 4: Guaranteed and 100% production tested. These limits are used to calculate outgoing AQL levels.

Note 5: Guaranteed but not 100% production tested. These limits are not used to calculate outgoing AQL levels.

Note 6: For single supply operation, the following conditions apply: $V^+ = 5V$, $V^- = 0V$, $V_{CM} = 2.5V$, $V_{OUT} = 2.5V$.

Note 7: $C_L \leq 5 pF$.

Note 8: In order to achieve optimum AC performance, the input stage was designed without protective clamps. Exceeding the maximum differential input voltage results in reverse breakdown of the base-emitter junction of one of the input transistors and probable degradation of the input parameters (especially V_{OS} , I_{OS} and Noise).

Note 9: The average voltage that the weakest pin combinations (those involving Pin 2 or Pin 3) can withstand and still conform to the datasheet limits. The test circuit used consists of the human body model of 100 pF in series with 1500 Ω .

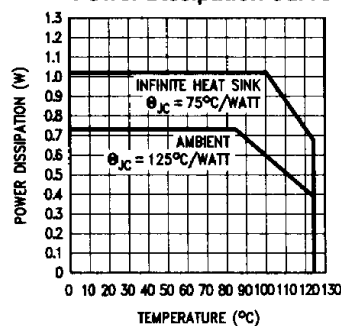
Note 10: $V_{IN} = 8V$ step. For supply = $\pm 5V$, $V_{IN} = 5V$ step.

Note 11: Voltage Gain is the total output swing (20V) divided by the input signal required to produce that swing.

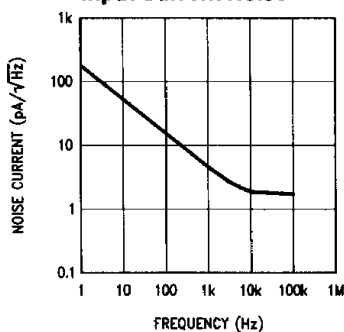
Typical Performance Characteristics $R_L = 10k$ and $T_A = 25^\circ\text{C}$ unless otherwise specified

LH4161A/LH4161/LH4161C

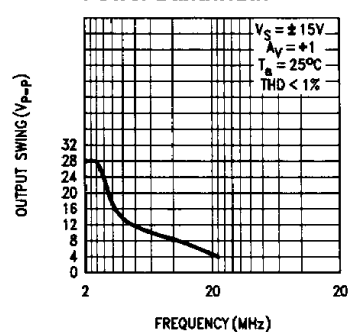
Power Dissipation Curve



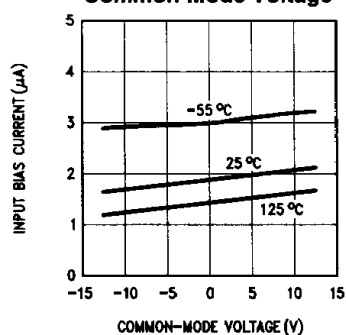
Input Current Noise



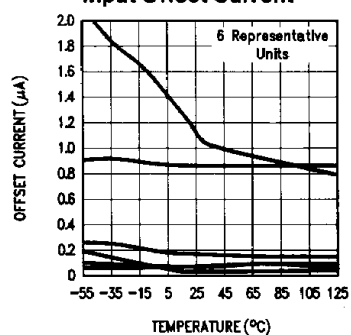
Power Bandwidth



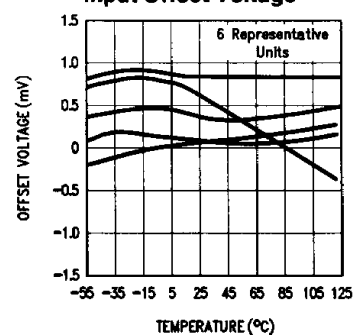
Bias Current vs Common-Mode Voltage



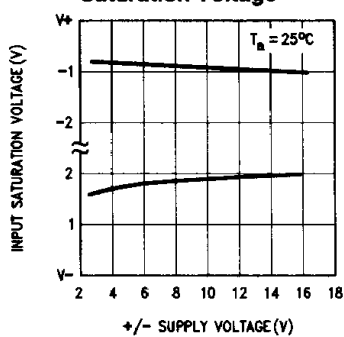
Input Offset Current



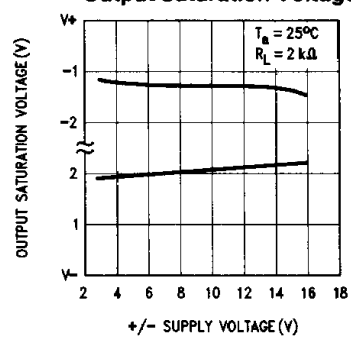
Input Offset Voltage



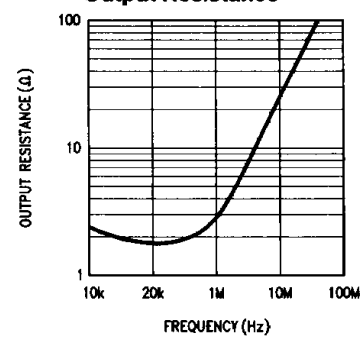
Common-Mode Input Saturation Voltage



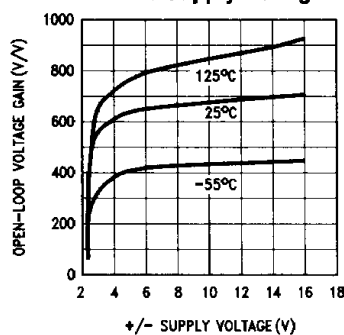
Output Saturation Voltage



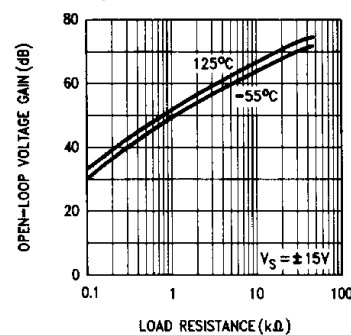
Output Resistance



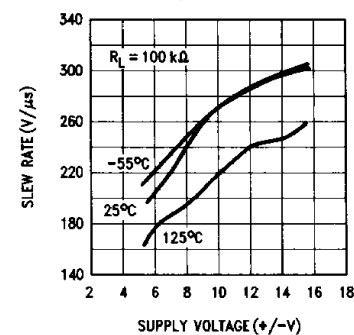
Gain vs Supply Voltage



Voltage Gain vs Load Resistance



Positive Slew Rate



TL/K/9767-5

The graph shows the input noise voltage of the AD8429 as a function of frequency. The y-axis represents noise voltage in $\text{nV}/\sqrt{\text{Hz}}$ on a logarithmic scale from 10 to 100,000. The x-axis represents frequency in Hz on a logarithmic scale from 1 to 1,000,000. The noise voltage decreases from 1,000 $\text{nV}/\sqrt{\text{Hz}}$ at 1 Hz to a noise floor of about 15 $\text{nV}/\sqrt{\text{Hz}}$ at 100,000 Hz and higher.

Frequency (Hz)	Noise Voltage ($\text{nV}/\sqrt{\text{Hz}}$)
1	1,000
10	316
100	100
1k	31.6
10k	15.8
100k	15.8
1M	15.8

Negative Slew Rate

$R_L = 100\text{ k}\Omega$

SLEW RATE ($\text{V}/\mu\text{s}$)

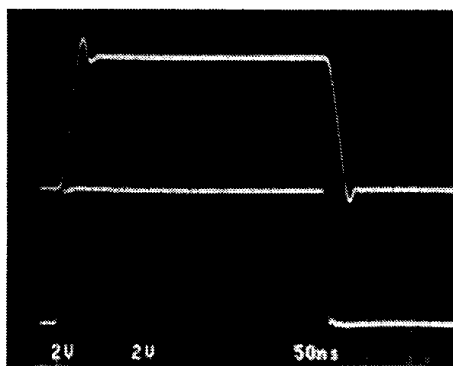
330
290
250
210
170
130

2 4 6 8 10 12 14 16 18

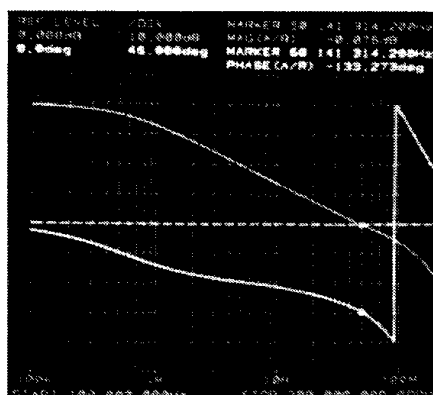
SUPPLY VOLTAGE ($\pm V$)

-55°C
25°C
125°C

Step Response; $A_V = +1$



Gain & Phase; $A_V = +100$



The LH4161 has been compensated for unity-gain operation. Since this compensation involved adding emitter-degeneration resistors in the op amp's input stage, the open-loop gain was reduced as the stability increased. Gain error due to reduced A_{VOL} is most apparent at high gains.

The LH4161 is unusually tolerant of capacitive loads. Most op amps tend to oscillate when their load capacitance is greater than about 200 pF (especially in low-gain circuits). However, load capacitance on the LH4161 effectively increases its compensation capacitance, thus slowing the op amp's response and reducing its bandwidth.

Power supply bypassing is not as critical for the LH4161 as it is for other op amps in its speed class. However, bypassing will improve the stability and transient response of the LH4161, and is recommended for every design. 0.01 μF to

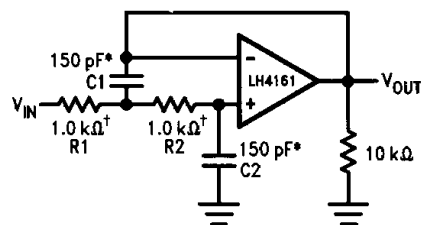
0.1 μF ceramic capacitors should be used (from each supply "rail" to ground); if the device is far away from its power supply source, an additional 2.2 to 10 μF of tantalum may be required for extra noise reduction.

Keep all leads short to reduce stray capacitance and lead inductance, and make sure ground paths are low-impedance, especially where heavier currents will be flowing. Stray capacitance in the circuit layout can cause signal coupling from one pin, input or lead to another, and can cause circuit gain to unintentionally vary with frequency.

Breadboarded circuits will work best if they are built using generic PC boards with a good ground plane. If the op amps are used with sockets, as opposed to being soldered into the circuit, the additional input capacitance may degrade circuit performance.

Typical Applications

1 MHz Low-Pass Filter
 $f_C = \frac{1}{2\pi} \sqrt{(R_1 R_2 C_1 C_2)}$

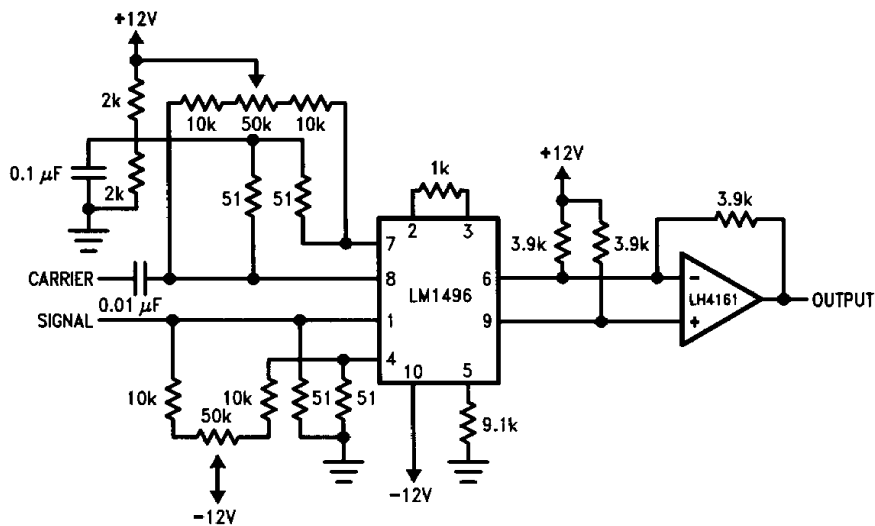


† 1% tolerance

*Matching determines filter precision

TL/K/9767-9

Modulator with Differential-to-Single-Ended Converter



TL/K/9767-10